

# SANYO Semiconductors DATA SHEET



# Monolithic Linear IC **LA77000V** — VHF Band RF Modulator (US3, 4ch Compatible)

### Overview

The LA77000V is a VHF band RF module that supports US3, 4ch Compatible.

### **Functions**

- RF VCO (AGC).
- RF Mixer.
- RF Buffer.
- Video clamp.
- White clipping.
- Audio FM.
- 4V regulator.
- Reference OSC.

### Specifications

#### **Maximum Ratings** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply rating	V <sub>CC</sub> max		7.0	V
Allowable power dissipation	Pd max	Ta ≤ 75°C	350*	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

\* Mounted to the glass epoxy resin made board (114.3mm×76.1mm×1.6mm)

### **Operating Conditions** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended operating voltage	VCC		5.0	V
Operating voltage range V <sub>CC</sub> op			4.5 to 5.5	V

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# **Electrical Characteristics/Operating Characteristics** at $Ta = 25^{\circ}C$ , $V_{CC} = 5.0V$ , Measured with US3ch unless otherwise specified

Parameter	Symbol	Conditions		Ratings		
Falameter		Conditions		typ	max	Un
Current drain 1	I <sub>CC</sub> 1	No signal, pin 6 high	28	41	53	m/
Current drain 2	I <sub>CC</sub> 2	No signal, pin 6 low	15	22	29	m/
Regulator voltage	Vreg	No signal	3.7	3.9	4.1	V
Antenna driver voltage	Vanton	Pin 6 high, 220 $\Omega$ load	3.2	3.5	3.8	V
Negative Resistance (pin7)	-R	Cl≤100	1.2	2.2		kΩ
RF type						
Video carrier frequency accuracy	Fp	Fp (US3ch): 61.25MHz	-25		25	kН
		X'tal accuracy 30ppm	-25		25	КП
Video carrier frequency stability	Fpt	X'tal accuracy 30ppm	-25		25	kH
		$Ta = 4^{\circ}C \text{ to } 38^{\circ}C$				
Video carrier output US	Pus	No signal (Note 1)	85.5	87.5	89.5	dB
Audio carrier output ratio	P/S	S: fp + 4.5MHz	14.5	16	17.5	dE
Audio 2 <sup>nd</sup> harmonic distortion	P/S2	S2: fp + 2 × 4.5MHz	50	65		dE
Audio 3 <sup>rd</sup> harmonic distortion	P/S3	S3: fp + 3 × 4.5MHz	45	55		dE
Chroma beat	P/CB	Vin = 3.58MHz, 0.6Vp-p	<u>c</u> e	74		٩L
		CB: fp + 920kHz	65	74		dE
Video harmonic distortion	P/V2	Vin = 1MHz, 1Vp-p	45	72		dE
		V2: fp + 2MHz	40	12		uL.
Video type		1	1		1	
Video modulation	Мр	Vin = Stair step, 1Vp-p	75	80	85	%
White clip level	W <sub>CL</sub>	Vin = Stair step, 1.5Vp-p	90	95	99	%
Differential gain	D <sub>G</sub>	Vin = 10-Stair step, 1Vp-p	-5		5	%
		(Note 2)	-5		5	70
Differential phase	DP	Vin = 10-Stair step, 1Vp-p	-5		5	°C
		(Note 2)			Ű	Ì
Video signal frequency response	R <sub>fv</sub>	Vin = CW, 1Vp-p	-1.1	-0.4	0.3	dE
	.,	0.75 MHz to 3.75MHz				
Video S/N	V <sub>S/N</sub>			50		dE
Audio type		4.2MHz LPF ON				
Audio carrier frequency accuracy	Fs	X'tal accuracy 30ppm	-5		5	kН
Audio modulation	Ms	Ain = 1kHz, 1Vp-p	-5		5	- KII
	119	(Note 3)	90	100	110	%
Maximum audio modulation	Msmx	THD < 3%	400			%
Audio distortion	THD	Ain = 1 kHz, 1Vp-p		0.4	2	%
Audio S/N	A <sub>S/N</sub>	Ain = 1 kHz, 1Vp-p				
	5/11	Vin = Color bar, 1Vp-p	45	50		dE

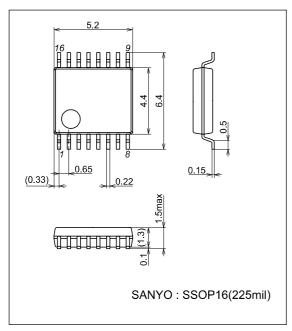
Note 1: 9.5dB added to the RFOUT value measured with a spectrum analyzer of the input impedance of  $50\Omega$ .

Note 2: Difference between 1 stair step and 8 stair step of 10 stair step.

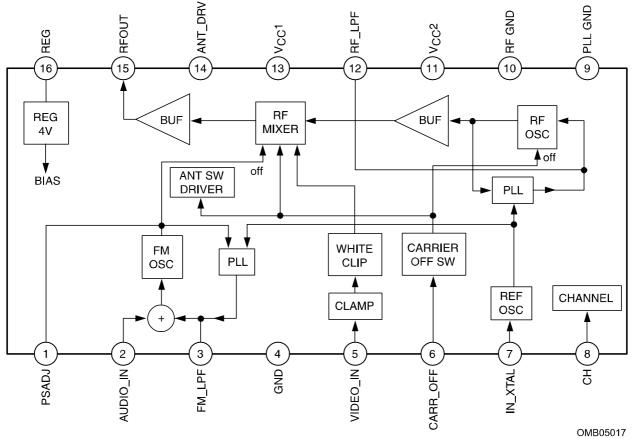
Note 3:  $100\% = \pm 25$ kHz modulation.

### Package Dimensions

unit : mm 3178B



## **Block Diagram**



JMB02017

## Pin equivalent circuit

-	-			1
Pin No.	Symbol	Voltage	Circuit	Remarks
1	P/S ADJ	2.7		Capacitor and additionally a Resistor may inserted between the circuit and GND attenuate the audio inter-carrier level.
2	AUDIO	0	2 100kΩ 7/7 7/7	FM audio Input.
3	FM LPF	2.2		Control pin of output FM oscilator for the PLL phase detector charge pump.
4	GND	0		
5	VIDEO	2.6		Video Input
	IN			Clamped with sink chip.
6	CARR OFF	-		Hi:14pin Hi RF Operating Lo:14pin Lo RF Stop

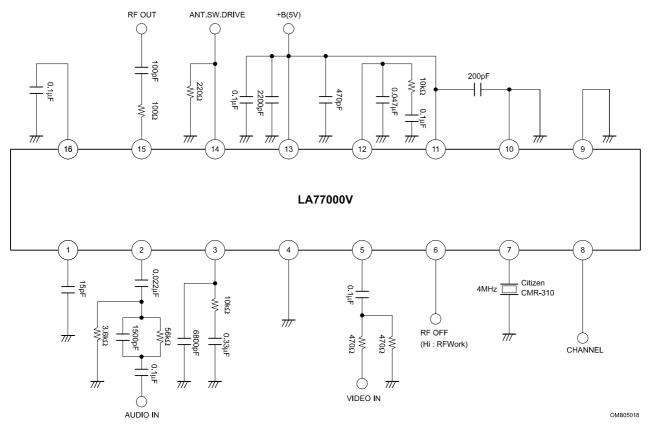
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Pin No.	Symbol	Voltage	Circuit	Remarks
7	IN XTAL	3.5	5PF 100Ω 500Ω 1 - W - W - W - W - W - W - W - W - W -	$\begin{array}{l} 4 \text{MHz} \mbox{ oscillator inserted between the circuit and GND.} \\ \text{External input of the 4MHz signal possible. Insertion of} \\ \mbox{ about 270k} \Omega \mbox{ resistor between the circuit and GND} \\ \mbox{ ensurescompatibility with 3.58MHz of VTR chroma} \\ \mbox{ sub-carrier.} \\ \mbox{ Insertion of about 270k} \Omega \mbox{ resistor between the circuit and} \\ \mbox{V}_{CC} \mbox{ ensurescompatibility with 27MHz of D-STB reference.} \end{array}$
8	СН	1.7	$33k\Omega$ (8) $17k\Omega$ (7)	CH selector pin US3: 4.2V or more US4: 2.7V to 3.8V
9	PLL GND	0		PLL type GND
10	RF GND	0		RF type GND
11	V <sub>CC</sub> 2	5.0		RF VCO type V <sub>CC</sub>
12	RF LPF	2.6	2.8V 1KΩ 1KΩ 1KΩ 2.2V <i>π</i> <i>π</i> <i>μ</i> <i>μ</i> <i>μ</i> <i>μ</i> <i>μ</i> <i>μ</i> <i>μ</i> <i>μ</i>	Control pin of output RF oscillator for the PLL phase detector charge pump.

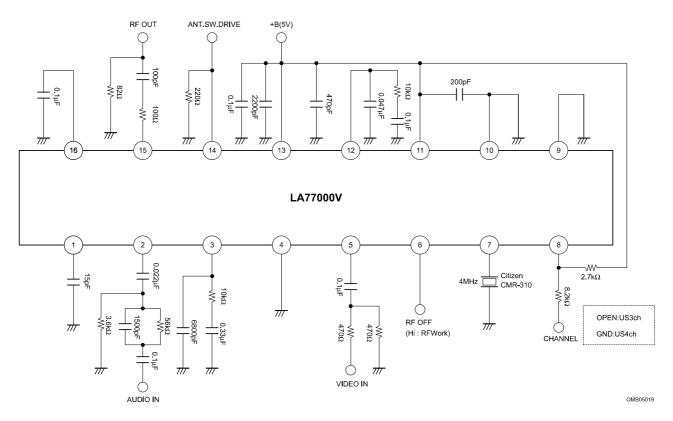
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Pin No.	Symbol	Voltage	Circuit	Remarks		
13	V <sub>CC</sub> 1	5.0		V <sub>CC</sub>		
14	ANT	3.5		Antenna SW driver pin.		
	DRV		50kΩ 1kΩ 1kΩ 1kΩ 100kΩ 100kΩ	15mA drive.		
15	RF OUT	3.0	15 1.5Ω	RF mixed signal output.		
16	REG	3.9	16 56.5kΩ 25kΩ	Regulator output.		

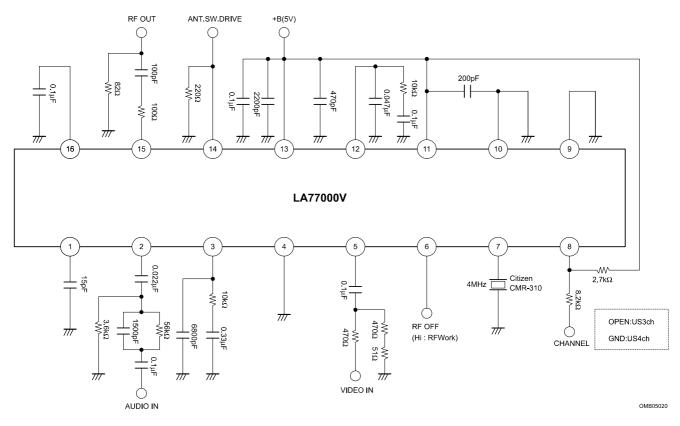
## **Test Circuit**



### Sample Application Circuit 1 (USch) for VCR







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